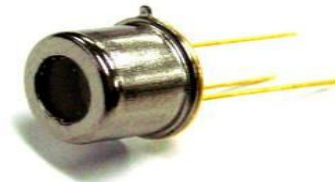




## UV-A Sensor GUVV-T20GD-U

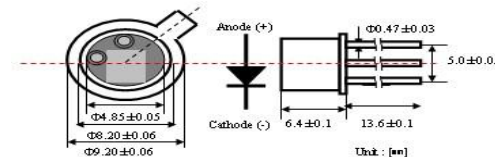


- Features**
- Indium Gallium Nitride Based Material
  - Schottky-type Photodiode
  - Photovoltaic Mode Operation
  - High Responsivity & Low Dark Current



- Applications**
- Full UV Band Monitoring
  - UV-A Lamp Monitoring
  - Sterilization Lamp Monitoring

### Outline Diagrams and Dimensions



### Absolute Maximum Ratings

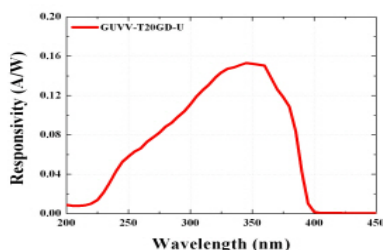
Parameter	Symbol	Min.	Max.	Unit	Remark
Storage Temperature	$T_{st}$	-40	90	$^{\circ}C$	
Operating Temperature	$T_{op}$	-30	85	$^{\circ}C$	
Reverse Voltage	$V_{r, max.}$		2	V	
Forward Current	$I_{f, max.}$		1	mA	
Optical Source Power Range	$P_{opt}$	0.01	100,000	$\mu W/cm^2$	UVA Lamp
Soldering Temperature	$T_{sol}$		260	$^{\circ}C$	within 10 sec.

※Notice: apply to us in the case that Optical Source Power is over  $100,000 \mu W/cm^2$ .

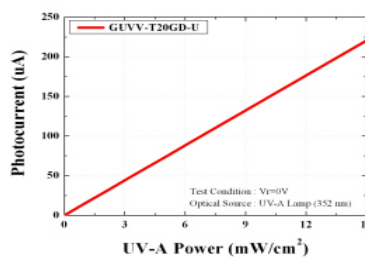
### Characteristics (at 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Dark Current	$I_d$			90	nA	$V_r = 0.1 V$
Photo Current	$I_{ph}$		14.7		$\mu A$	UVA Lamp, $1 mW/cm^2$
Temperature Coefficient	$I_{tc}$		0.1		$\%/^{\circ}C$	UVA Lamp
Responsivity	R		0.15		A/W	$\lambda = 352 nm, V_r = 0 V$
Spectral Detection Range	$\lambda$	230		395	nm	10% of R
Active area			6.894		$mm^2$	

### Responsivity Curve



### Photocurrent along UV Power



### Caution

- ESD can damage the device hence please avoid ESD.
- Insulate the cap of TO-CAN or it can cause malfunction of the device.